NX5P3363

USB PD and Type-C current-limited power switch

Rev. 1.1 — 7 June 2019

Product data sheet

1. General description

The NX5P3363 is a precision adjustable current-limited power switch for USB PD application. The device includes under voltage lockout, over-temperature protection, and reverse current protection circuits to automatically isolate the switch terminals when a fault condition occurs. The 29 V tolerance on VBUS pin ensures the device is able to work on a USB PD port; a current limit input (ILIM) pin defines the overcurrent limit threshold; an open-drain fault output $(\overline{\text{FLT}})$ indicates when a fault condition has occurred.

The overcurrent limit threshold can be programmed from 400 mA to 3.3 A, using an external resistor between the ILIM pin and GND pin. In the over current condition, the device will clamp the output current to the value set by ILIM and keep the switch on while asserting the FLT flag.

To minimize current surges during normal turn on, the device has built in soft start by limiting the power switch turn on slew rate. However, user can disable the soft start and request a fast output by pulling FO pin HIGH.

A fast RCP recovery circuit has been added to the switch to prevent reverse current flowing back to power source at all times. When exiting from reverse current protection state, the power MOSFET will turn on within 50 us. The fast RCP recovery ensures the voltage on VBUS doesn't drop too much in a power source swap application.

NX5P3363 is offered in a 2.2 x 2.2 mm, 16 bump WLCSP package.

2. Features and benefits

- VIN supply voltage range from 4.0 V to 5.5 V
- All time reverse current protection with ultra fast RCP recovery
- Adjustable current limit from 400 mA to 3.3 A
- Clamped current output in overcurrent condition
- 29 V high voltage tolerance on VBUS pin
- Low ON resistance of the power FETs: 35 mΩ (typical) in total
- Surge protection: IEC61000-4-5 exceeds ±80 V on VBUS
- Over temperature protection
- Safety approvals
 - ◆ UL 62368-1, 2nd edition, file no. 20170804-E470128
 - ◆ IEC 62368-1, 2nd edition, file no. DK-65509-UL
- ESD protection
 - ◆ IEC61000-4-2 contact discharge exceeds 8 kV on VBUS
 - ♦ HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
 - CDM AEC standard Q100-01 (JESD22-C101E) exceeds 500 V



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■ Specified from –40 °C to +85 °C ambient temperature

3. Applications

- Notebook, ultrabook and desktop
- USB PD and Type C port/hubs
- Tablet and smart phone

4. Ordering information

Table 1. Ordering information

Type number	•	Package	Package				
	marking	Name	Description	Version			
NX5P3363UK	X5PT6		wafer level chip-scale package; 16 bumps; 2.2 x 2.2 mm x 0.555 mm (backside coating included)	SOT1394-3			

4.1 Ordering options

Table 2. Ordering options

Type number	Orderable part number	Package	J	Minimum order quantity	Temperature
NX5P3363UK	NX5P3363UKZ	WLCSP16	REEL 7" Q1/T1 *SPECIAL MARK CHIPS DP	3000	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$

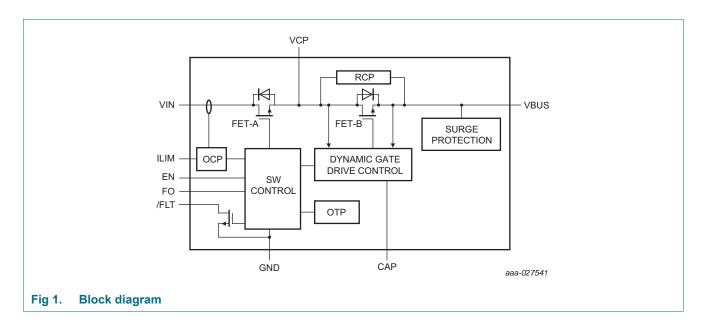
5. Marking

Table 3. Marking

Line	Marking	Description
A	X5PT6	basic type name
В	mmmmmnn	wafer lot code (mmmmmm) and wafer number (nn)
С	XtDYYWW	manufacturing code:
		X = foundry location
		t = assembly location
		D = RoHS code (dark green)
		YY = assembly year code
		WW = assembly week code

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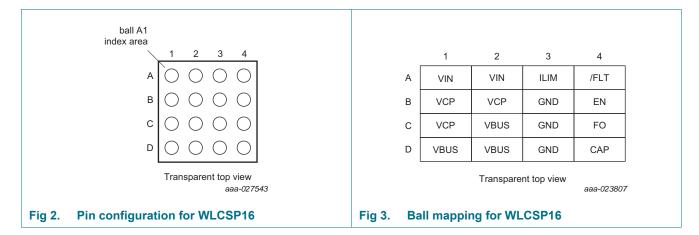
6. Functional diagram



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7. Pinning information

7.1 Pinning



7.2 Pin description

Table 4. Pin description

Symbol	Pin	Description
VIN	A1, A2	input voltage
VCP	B1, B2, C1	Central point of two power MOSFETs.
VBUS	C2, D1, D2	output voltage
ILIM	A3	current limiter. connect a resistor to GND to adjust the current limit level
FLT	A4	fault condition indicator (open-drain output)
EN	B4	enable input (active HIGH with internal 1 $M\Omega$ pull down resister)
GND	B3, C3, D3	ground (0 V)
FO	C4	Fast turn on. Pull this pin HIGH to enable fast turn-on feature. 1 $\text{M}\Omega$ pull down resister integrated.
CAP	D4	connect a capacitor to GND

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8. Functional description

Table 5. Function table [1]

EN	FO	VIN	FLT	Main Power Switch
Χ	X	< 4.0 V	Z	under voltage lockout, Switch open
L	X	4.0 V to 5.5 V	Z	disabled; switch open
Н	L	4.0 V to 5.5 V	Z	enabled; switch turns on with slew rate control
Н	Н	4.0 V to 5.5 V	Z	enabled; switch turns on without slew rate control; fast turn on
Н	Х	4.0 V to 5.5 V	L	In current limit condition or over temperature protection
Χ	X	4.0 V to 5.5 V and VIN <= VBUS	Z	Reverse protection; switch open

^[1] H = HIGH voltage level; L = LOW voltage level.

8.1 EN input

When the EN is set LOW, all the FETs will be disabled, the device will enter low-power mode disabling all protection circuits and setting the FLT output high impedance. When EN is set HIGH, all protection circuits will be enabled and then, if no fault condition exists, the main power MOSFETs will be turn on.

8.2 Fast recovery Reverse-Current Protection (RCP)

NX5P3363 uses dynamic gate drive control loop to implement reverse-current protection. During normal operation, device will always try to regulate the VBUS output voltage to be VIN - 70 mV.

When the load current produces a drop voltage greater than 70 mV, the gate control loop will drive the power MOS to lower its Rdson to try to achieve the 70 mV. In the heavy load condition, the gate control loop will keep increasing the gate driving current of the MOSFET until it is fully on and will remain fully on if the voltage drop at that time still exceeds 70 mV.

In light load condition, when the drop voltage is below 70 mV, the gate control loop will reduce the gate driving current to increase the Rdson to try to achieve the 70 mV drop voltage, which leads to the complete shutdown of the power MOSFET in reverse voltage condition.

If VBUS voltage is higher than VIN when enabling the device, the power MOSFET will never turn on. The device will always do pre-check before switching on the power MOSFETs.

In the RCP state, EN is HIGH; when the VBUS drops below VIN, the device will exit the RCP state and turn on the power FET again within 50 us. The fast recovery of the power MOSFET is assisted by the external boost capacitor at CAP pin. The boost capacitor will be charged whenever EN is pulled HIGH.

The input voltage level of FO pin has nothing to do with RCP recovery time.

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8.3 VBUS Hot Plug in Reverse Current Protection

The RCP circuit, together with dynamic gate drive control circuit, act like an "ideal diode". That protects the VIN lift by the reverse current when VBUS have a hot plug in as following conditions and limit the VIN voltage lift <400mV refer to NX5P3363 ground pin,

- VBUS<24V, plug in when NX5P3363 is on
- C_{IN} is in the range of 57uF 100uF
- C_{BUS} is in the range of 10uF 22uF

If the VBUS, C_{IN} , C_{BUS} are not in the range or conditions, there may have more reverse current and the VIN voltage lift depends on the conditions.

8.4 Fast Turn ON

In order to reduce the power on inrush current, NX5P3363 has deployed slew rate control for normal turn on; there will be around 2 ms rising time. However, in the fast role swap application, fast turn on is requested. The customer can achieve this by pulling FO pin "High". By doing this, rise time will be reduced to the 100 us level. There is an internal 1 $M\Omega$ pull-down resister on this pin. The fast turn on is achieved by turn off short circuit protection and OCP feature in the fast start stage, that is typically $220\mu s$. It is recommended to add 10uF capacitor close to VIN pin to limit the inrush current in fast turn on mode.

The feature is only applied for fast role swap, and FO pin should be controlled by USB PD PHY. When a fast role swap event is detected by USB PD PHY, the FO pin should be pull "High" first, then enable the EN pin of NX5P3363 when the FRS is requested. Depending on the voltage on VBUS, there will be two scenarios:

V(VBUS) > V(VIN)

The switch will enter RCP mode. Once the voltage on VBUS drops below VIN voltage, switch will be immediately turn on within 50 us.

V(VBUS) <= V(VIN)

The switch will perform a fast turn ON as the FO is HIGH; the turn on time is 150 us.

When fast role swap is finished and NX5P3363 is in all the other conditions, FO pin should be remaining as "Low" to limit the inrush current.

8.5 Under-voltage lock-out

Independently of the logic level on the EN pin, the under-voltage lockout (UVLO) circuit disables the N-channel MOSFET and enters low power mode until the input voltage reaches the UVLO turn-on threshold VUVLO.

8.6 ILIM

The overcurrent protection circuit's (OCP) trigger value I_{OCP} can be set using an external resistor R_{ILIM} connected between ILIM pin and GND pin. When EN is set HIGH and the ILIM pin is grounded, the N-channel MOSFET will be disabled. The I_{OCP} setting is given in Table 12.

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8.7 Main Power FET Overcurrent protection (OCP)

The device offer over current protection when enabled, three possible overcurrent conditions can occur. These conditions are:

- Overcurrent at start-up, I_{SW} > I_{OCP} when enabling the N-channel MOSFET.
- Overcurrent when enabled, I_{SW} > I_{OCP} when the N-channel MOSFET is enabled.
- · Short circuit when enabled, ISW exceeds short circuit conditions

In the over current condition, because the device clamps the output current rather than completely shut down the switch, the power dissipation on the device might be increased which could lead to over temperature protection (see Section 8.9).

8.7.1 Overcurrent at start-up

If the device senses a VBUS short to GND or overcurrent while enabling the N-channel MOSFET, OCP is triggered. It limits the output current to I_{OCP} and after the de-glitch time sets the FLT output LOW.

8.7.2 Overcurrent when enabled

If the device senses I_{SW} exceeds I_{OCP} when enabled, OCP is triggered. It limits the output current to I_{OCP} and after the de-glitch time sets the \overline{FLT} output LOW. As a consequence, limiting the output current will reduce $V_{O(VBUS)}$.

8.7.3 Short circuit when enabled

If the current through switch exceeds 7.5A (typical), the short circuit protection is triggered. That disables the N-channel MOSFET immediately. It then enables the N-channel MOSFET again, output current is limited to I_{OCP} and after the de-glitch time the FLT output is set LOW. Thermal protection will be triggered due to the big power consumption on the device.

In the customer specific application case, the short circuit protection ensures the VIN voltage keeping above 4.5V at the following short circuit testing.

- C_{IN} = 57 μ F, VBUS short to GND directly by a metal tweezer, that means the short resistor to ground is typically 40m Ω
- VIN connected to customer specified DC-DC

8.8 FLT output

The FLT output is an open-drain output that requires an external pull-up resistor. The FLT output will be set LOW to indicate an OCP or OTP condition has occurred. The FLT output will return to the high impedance state automatically once the fault condition is removed. An internal 8 ms de-glitch circuit for the overcurrent protection is used when entering fault conditions. Over-temperature condition doesn't have de-glitch time, the FLT signal will be asserted immediately. The RCP circuit won't trigger FLT signal.

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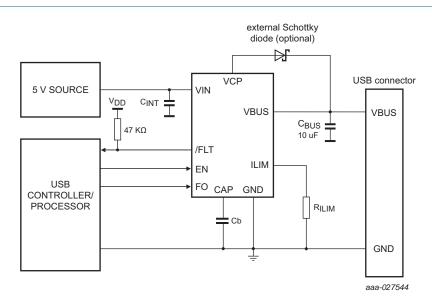
8.9 Over-temperature protection

If the device temperature exceeds 140 °C when EN is set HIGH, the over-temperature protection (OTP) circuit will disable the Power MOSFET and indicate a fault condition by setting the FLT pin LOW. Any transition on the EN pin will have no effect. Once the device temperature decreases to below 115 °C the device will return to the defined state.

In the overcurrent limiting condition, the increased power dissipation on the device will result the OTP, especially in the output-short-to-GND error.

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9. Application diagram



A 0.1 μ F ceramic capacitor (C_{INT}) is required for local decoupling. Higher capacitor values C_{INT} further reduce the voltage drop at the input. When driving inductive loads, a larger capacitance C_{INT} prevents voltage spikes from exceeding absolute maximum voltage of VIN. The CBUS capacitor should be placed as closer as possible to VBUS pin.

The recommended Cb is 1 nF with at least 16 V voltage tolerance.

The external Schottky diode is optional, NX5P3363 works well without it. To improve the lowest VBUS voltage during fast role swap, it is recommended to add a lower forward voltage diode, for example VF = 0.3 V.

Fig 4. Application diagram

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10. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
VI	input voltage	VBUS	[1]	-0.5	+29	V
		VIN; VCP; ILIM; EN; FO	[1]	-0.5	+6	V
		CAP	[1]	-0.5	+12	V
	peak voltage tolerance	VBUS; 20μs pulse width, 1s interval	[1]	-0.5	+34	V
Vo	output voltage	FLT	[1]	-0.5	+6	V
I _{IK}	input clamping current	input EN: V _{I(EN)} < -0.5 V		-50	-	mA
I _{I(source)}	input source current	input ILIM		-	1	mA
I _{SK}	switch clamping current	input VIN: V _{I(VIN)} < -0.5 V		-50	-	mA
		output VOUT: V _{O(VBUS)} < -0.5 V		-50	-	mA
I _{SW}	Main Power switch continuous current	V _{SW} > -0.5 V	[2]	-	3.6	А
T _{j(max)}	maximum junction temperature			-40	+125	°C
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation		[3]	-	1.7	W

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

^[2] Internally limited.

^[3] The (absolute) maximum power dissipation depends on the junction temperature T_j . Higher power dissipation is allowed in conjunction with lower ambient temperatures. The conditions to determine the specified values are $T_{amb} = 25$ °C and the use of a two layer PCB.

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11. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
VI	input voltage	VIN	4.0	5.5	V
		EN; FO	0	5.5	V
		VBUS (OFF state)	0	23	V
Vo	Output voltage	VBUS; FLT	0	5	V
I _{SW}	switch current	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$	0	3	Α
I _{O(sink)}	output sink current	FLT	0	10	mA
R _{ILIM}	current limit resistance	ILIM pin to GND	14.3	140	kΩ
C _{Bus}	VBUS output capacitance	VBUS to GND	10	100	μF
T _{amb}	ambient temperature		-40	+85	°C

12. Thermal characteristics

Table 8. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	[1]	58.4	K/W

^[1] R_{th(j-a)} is dependent upon board layout. To minimize R_{th(j-a)}, ensure all pins have a solid connection to larger copper layer areas. In multi-layer PCBs, the second layer should be used to create a large heat spreader area below the device. Avoid using solder-stop varnish under the device.

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13. Static characteristics

Table 9. Static characteristics

At recommended operating conditions; $V_{I(VIN)} = V_{I(EN)}$, $R_{FAULT} = 10 \text{ k}\Omega$ unless otherwise specified; Voltages are referenced to GND (ground = 0 V). See <u>Figure 9</u>

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V _{IH}	HIGH-level input voltage	EN; FO; $V_{I(VIN)} = 4.0 \text{ V to } 5.5 \text{ V};$	1.2	-	-	V
V _{IL}	LOW-level input voltage	EN; FO; V _{I(VIN)} = 4.0 V to 5.5 V;	-	-	0.4	V
l _l	input leakage current	EN; FO; V _{I(VIN)} = 5.0 V;	-	-	7	μА
I _(VIN)	supply current	VBUS open; V _{I(VIN)} = 5.0 V				
		EN = GND (low power mode);	-	3	55	μΑ
		$EN = V_{I(VIN)}$; $R_{ILIM} = 33 \text{ k}Ω$	-	1.3	1.7	mA
		$EN = V_{I(VIN)}$; $R_{ILIM} = 16 kΩ$	-	1.35	1.7	mA
I _{S(OFF)}	VBUS OFF-State leakage current	$V_{I(VIN)} = 5.0 \text{ V}; V_{I(VBUS)} = 0 \text{ V}; \text{EN} = \text{LOW}$ [2]	-5	-0.1	-	μА
	VIN OFF-state leakage current	V _{I(VBUS)} = 5.0 V; V _{I(VIN)} = 0 V; EN = LOW [2]	-2	-0.1	-	μΑ
		$V_{I(VBUS)} = 20 \text{ V}; V_{I(VIN)} = 0 \text{ V}; \text{EN} = LOW $ [2]	-2	-0.1	-	μΑ
I _{S(ON)}	FET-B leakage current in RCP	$V_{I(VIN)} = 5 \text{ V}; V_{I(VBUS)} = 20 \text{ V}; \text{ EN} = 5 \text{ V}$ [2]	-2	-0.1	-	μА
R _{pd}	Pull-down resistance	EN; FO; V _{I(VIN)} = 5 V	-	1	-	МΩ
V_{UVLO}	under voltage lockout voltage	VIN pin	-	3.6	3.8	V
V _{hys(UVLO)}	under voltage lockout hysteresis voltage		-	100	-	mV
V _{OL}	LOW-level output voltage	FLT; I _O = 4 mA	-	-	0.3	V
C _{I(EN)}	EN pin		-	3	-	pF
C _{I(FO)}	FO pin		-	4	-	pF

^[1] Typical values are measured at T_i = 25 °C.

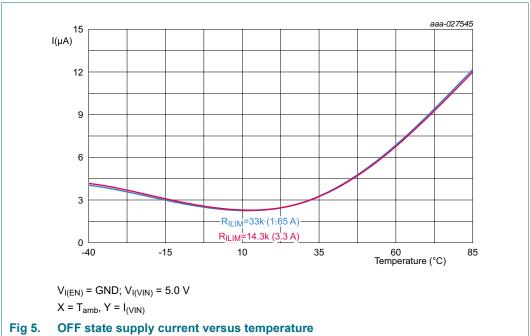
^[2] Currents are defined with respect to conventional current flow into the respective terminal. Negative value means the current flows out of the respective terminal of the chip.

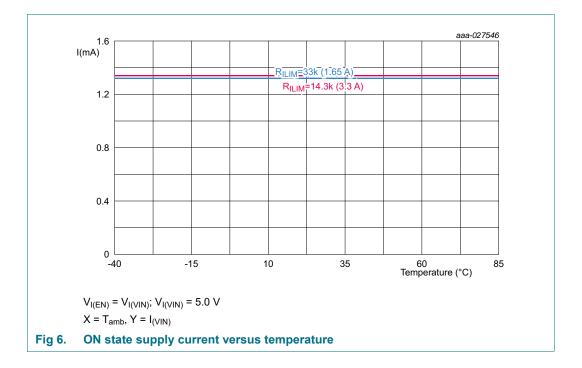
^[3] Guaranteed by design

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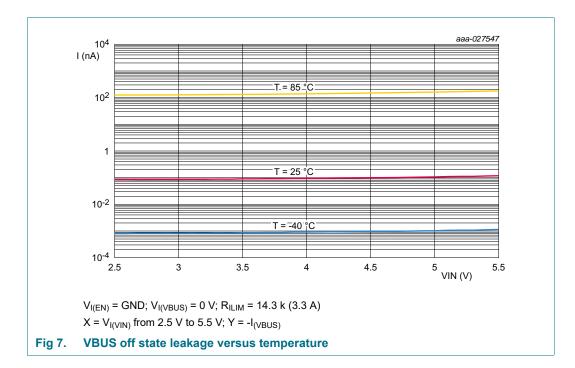
13.1 Graphs

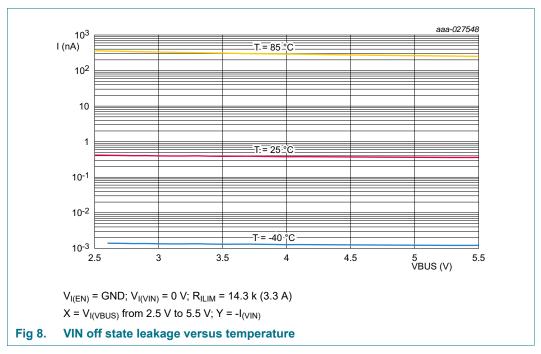




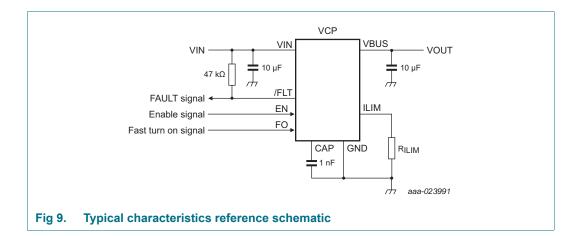
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13.2 Thermal shutdown

Table 10. Thermal shutdown

 $V_{I(VIN)} = V_{I(EN)}$, $R_{FAULT} = 10 \text{ k}\Omega$ unless otherwise specified; Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{th(ots)}	over temperature shutdown threshold temperature	$V_{I(VIN)} = 4.0 \text{ V to } 5.5 \text{ V}$	-	140	-	°C
T _{th(otp)hys}	hysteresis of over temperature protection threshold temperature	$V_{I(VIN)} = 4.0 \text{ V to } 5.5 \text{ V}$	-	25	-	°C

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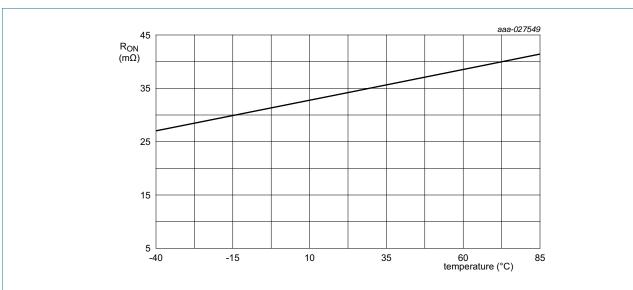
13.3 ON resistance

Table 11. ON resistance

 $V_{I(VIN)} = V_{I(EN)}$, $R_{FAULT} = 10 \text{ k}\Omega$ unless otherwise specified; Voltages are referenced to GND (ground = 0 V). See <u>Figure 9</u>

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{ON}	ON resistance	$R_{FETA} + R_{FETB}$; $V_{I(VIN)} = 4.0$ to 5.5 V; see <u>Figure</u> 10				
		T _{amb} = 25 °C	-	35	42	mΩ
		T _{amb} = -40 °C to +85 °C	-	-	49	mΩ

13.4 ON resistance graphs



 $X = T_{amb}$, Y = Ron; $V_{I(VIN)} = 5.0 V$

Fig 10. Typical ON resistance versus temperature

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13.5 Current limit

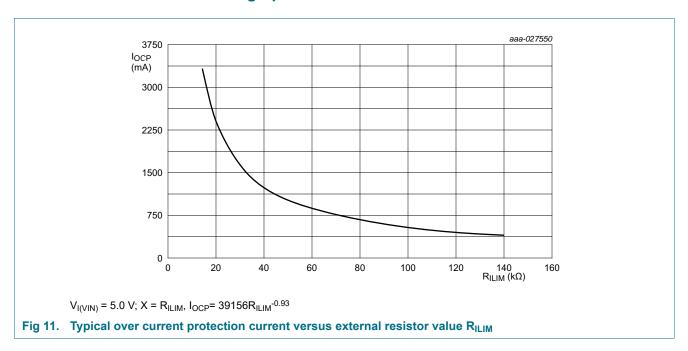
Table 12. Current limit

 $V_{I(VIN)} = V_{I(EN)}$, $R_{FAULT} = 10 \text{ k}\Omega$ unless otherwise specified; Voltages are referenced to GND (ground = 0 V). See <u>Figure 9</u>

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit		
I _{OCP}	over current protection current	$V_{I(VIN)}$ = 4.0 to 5.5 V; T_{amb} = -40 °C to +85 °C; see Figure 11,						
		R _{ILIM} = 140 kΩ	330	400	465	mA		
		$R_{ILIM} = 97.6k\Omega$	480	550	625	mA		
				$R_{ILIM} = 51 \text{ k}\Omega$	915	1000	1107	mA
		$R_{ILIM} = 30 \text{ k}\Omega$	1505	1640	1780	mA		
		$R_{ILIM} = 22.1 \text{ k}\Omega$	2024	2200	2398	mA		
		$R_{ILIM} = 18.2k\Omega$	2450	2640	2820	mA		
		R _{ILIM} = 14.3 kΩ	3100	3300	3531	mA		
		ILIM shorted to VIN	168	210	273	mA		

^{[1] 1%} tolerance resistor is recommend for R_{ILIM}

13.6 Current limit graphs



14. Dynamic characteristics

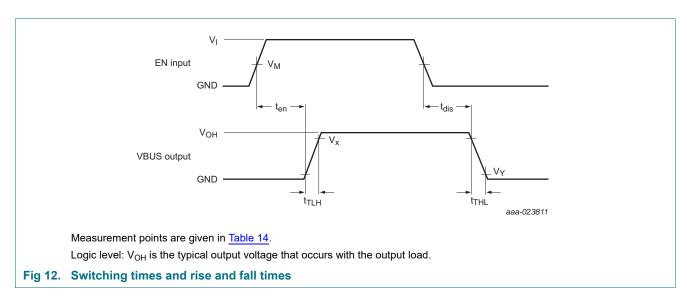
Table 13. Dynamic characteristics

At recommended operating conditions; $V_{I(VIN)} = V_{I(EN)}$, $R_{FAULT} = 10 \text{ k}\Omega$ unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
	LOW to HIGH output transition time	VBUS; $V_{I(VIN)}$ = 5.0 V; C_L = 10 uF; R_L = 100 Ω ; see <u>Figure 12</u> and <u>Figure 13</u>				
		V _{I(FO)} = GND	-	1.5	-	ms
		V _{I(FO)} = 5.0 V	-	50	100	μS
	HIGH to LOW output transition time	VOUT; $C_L = 10uF$; $R_L = 100 \Omega$; see Figure 12 and Figure 13				
		V _{I(VIN)} = 5.0 V	-	2.2	-	ms
t _{en} en	enable time	EN to VOUT; $C_L = 10uF$; $R_L = 100 \Omega$; seeFigure 14 and Figure 15				
		$V_{I(VIN)} = 5.0 \text{ V}; V_{I(FO)} = \text{GND}$	-	0.75	-	ms
		$V_{I(VIN)} = 5.0 \text{ V}; V_{I(FO)} = 5.0 \text{ V}$	-	60	-	μS
t _{dis}	disable time	EN to VOUT; $V_{I(VIN)} = 5.0 \text{ V}$; $C_L = 10 \text{ uF}$; $R_L = 100\Omega$; see Figure 16 and Figure 17	-	90	-	μs
t _{on(RCP)}	RCP recovery time	$V_{I(VIN)}$ = 5.0 V; EN = HIGH; From VBUS drops below VIN to FET-B ON; C_L = 10uF	-	15	50	μS
t _{dis(RCP)}	RCP turn off time	FET-B RCP turn OFF time	1 -	0.3	-	μS
t _{degl}	de-glitch time	FLT in OCP; V _{I(VIN)} = 5 V; see <u>Figure 20</u> to <u>Figure 21</u>	-	8	-	ms
t _{short(OCP)}	OCP short circuit protection response time	V _{I(VIN)} = 5.0 V; C _{BUS} =10uF; Measure current at VBUS side	-	5	-	μS

^[1] Typical values are measured at T_j = 25 °C.

14.1 Waveform and test circuits

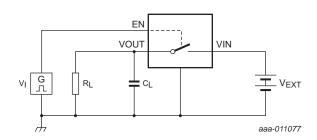


^[2] Guaranteed by design

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Table 14. Measurement points

Supply voltage	EN Input	Output		
V _{I(VIN)}	V_{M}	V _X	V _Y	
5.0 V	$0.5 \times V_{I(EN)}$	$0.9 \times V_{OH}$	$0.1 \times V_{OH}$	



Test data is given in Table 15.

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 V_{EXT} = External voltage for measuring switching times.

Fig 13. Test circuit for measuring switching times

Table 15. Test data

Supply voltage	EN Input	Load	
V _{EXT}	V _{I(EN)}	CL	R_L
5.0 V	0 to V _{I(VIN)}	10 μF	100 Ω

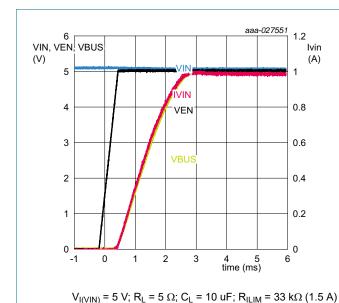
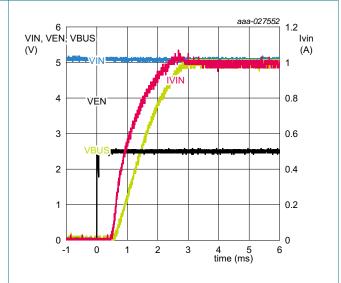


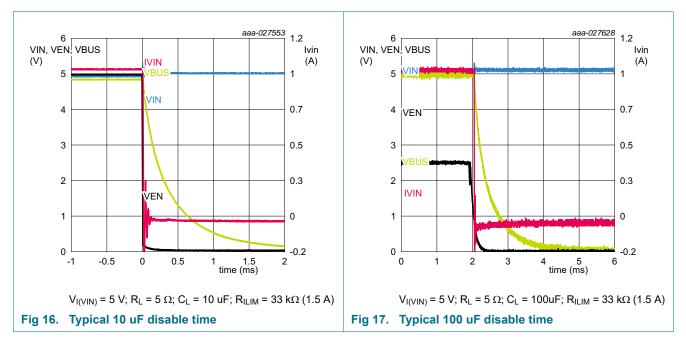
Fig 14. Typical 10 uF enable time versus inrush current

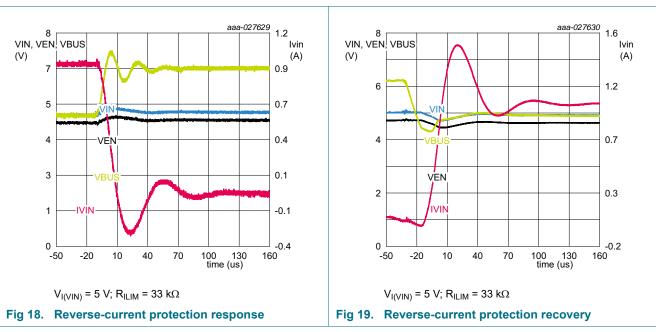


 $V_{I(VIN)}=5~V;~R_L=5~\Omega;~C_L=100uF;~R_{ILIM}=33~k\Omega~(1.5~A)$ Fig 15. Typical 100 uF enable time versus inrush

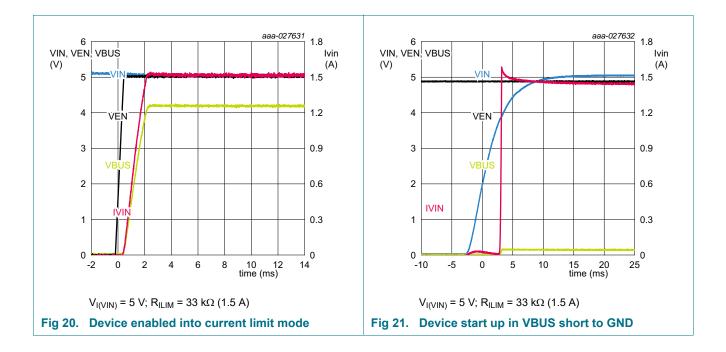
current

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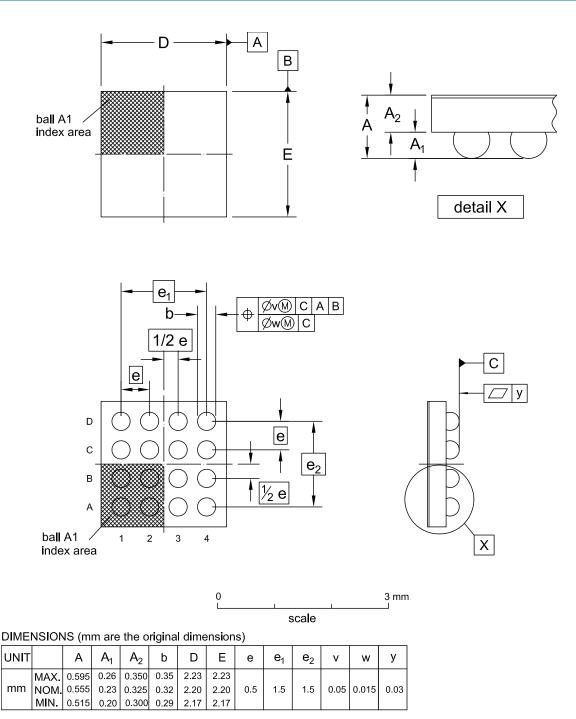




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15. Package outline



NOTE: Backside coating 25 um

Fig 22. Package outline SOT1394-3 (WLCSP16)

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16. Abbreviations

Table 16. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
CDM	Charged Device Model
HBM	Human Body Model
USB	Universal Serial Bus
VOIP	Voice over Internet Protocol

17. Revision history

Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX5P3363 v.1.1	20190607	Product data sheet	-	NX5P3363 v.1
Modifications:	<u>Table 6 "Limiting values"</u> , V _I : Created separate row for pin CAP			
NX5P3363 v.1	20170904	Product data sheet	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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